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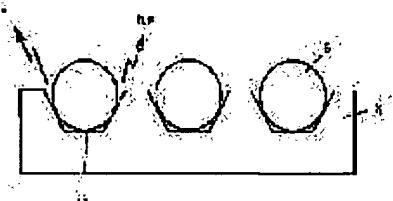
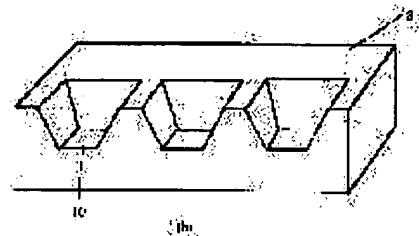
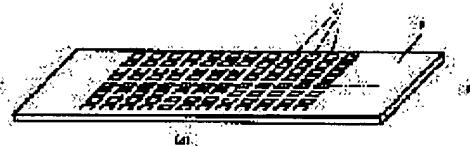
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## (54) ELECTROCHEMILUMINESCENCE DETECTING CELL

### (57) Abstract:

**PROBLEM TO BE SOLVED:** To obtain an electrochemiluminescence detecting cell whose reproducibility is high and which obtains a high S/N ratio by a method wherein a recessed part is formed on a working electrode and magnetic beads are captured by the recessed part in a one-to-one manner so as to emit light.

**SOLUTION:** A plurality of recessed parts 9 are formed on a conductive electrode plate 8. The size of every recessed part 9 is matched to the size of every magnetic bead 6. The bottom face 10 and side faces by every recessed part 9 act as electrodes. It is required to completely remove every bead 6 which is captured once when a next measurement is performed. When the area of the bottom face 10 is made smaller than that of an opening part in such a way that a cross-sectional shape is an inverted trapezoid, every bead is removed efficiently. It is required to deliver electrons with reference to every working electrode so that a luminescent reagent can emit light. As a result, only the luminescent reagent which is close of every working electrode out of luminescent reagents which are fixed to every bead 6 participates in luminescence. In every working electrode, at least four places on side faces of every recessed part 9 are obtained as points coming into contact with every bead 6, every bead 6 can come into contact with the bottom face 10 when the structure of every recessed part is made optimum, and every bead 6 owns five contact points in common. Since electrochemiluminescence is generated in every contact



point, it can be measured in a high S/N ratio.

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## LEGAL STATUS

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